



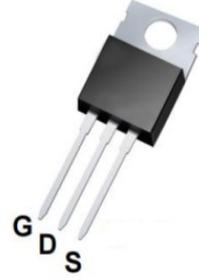
XNT031N04T

40V N-Channel MOSFET

1.Features

- V_{DS} 40V
- I_D (at $V_{GS}=10V$) 140A
- $R_{DS(on)}$ (at $V_{GS}=10V$) 2.4m Ω (Typ)

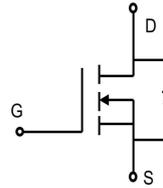
TO-220



1. Gate
2. Drain
3. Source

2.Mechanical Data

- Case:Molded Plastic,TO-220;
- Epoxy:UL 94V-0 rate flame retardant
- Terminals:Plated Leads Solderable per MIL-STD-750,Method-2026.
- Marking: marked on body.
- Mounting Position : Any.



3.Maximum Ratings and Electrical Characteristics

Electrical Characteristics ($T_J=25^{\circ}C$ unless otherwise noted)

Characteristics		Symbol	Ratings	Unit
Drain-Source Voltage		V_{DS}	40	V
Gate-Source Voltage		V_{GS}	± 20	V
Drain Current-Continuous	$T_C=25^{\circ}C$	I_D	140	A
	$T_C=100^{\circ}C$		99	
Maximum Power Dissipation		P_D	115	W
Single Pulsed Avalanche energy ⁽¹⁾		E_{AS}	560	mJ
Junction and Storage Temperature Range		T_J, T_{stg}	-55 to +150	$^{\circ}C$
Thermal Characteristics				
Parameter	Symbol	Typ	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	-	1.3	$^{\circ}C/W$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	-	62	$^{\circ}C/W$



Characteristics	Symbol	Test conditions	Min	TYP	Max	Unit
STATIC PARAMETERS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	40	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=40V, V_{GS}=0V$	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{GS}=V_{DS}, I_D=250\mu A$	1	1.7	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=20A$	-	2.4	3.1	m Ω
		$V_{GS}=4.5V, I_D=20A$	-	3.5	4.5	
DYNAMIC PARAMETERS						
Input Capacitance	C_{iss}	$V_{DS}=20V$	-	6460	-	pF
Output Capacitance	C_{oss}	$V_{GS}=0V$	-	455	-	
Reverse Transfer Capacitance	C_{rss}	$f=1.0MHz$	-	276	-	
SWITCHING PARAMETERS						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=20V, V_{GS}=10V$ $R_L=1\Omega; R_G=3\Omega;$	-	18	-	nS
Turn-on Rise Time	t_r		-	4.4	-	
Turn-off Delay Time	$t_{d(off)}$		-	67	-	
Turn-off Fall Time	t_f		-	9.5	-	
Total Gate Charge	Q_g	$V_{DS}=20V, I_D=20A$ $V_{GS}=10V$	-	112	-	nC
Gate-Source Charge	Q_{gs}		-	16.6	-	
Gate-Drain Charge	Q_{gd}		-	26.5	-	
Diode Forward Voltage	V_{SD}	$I_{SD}=1A, V_{GS}=0V$	-	-	1.2	V
Gate resistance	R_g	$V_{GS}=0V, V_{DS}=0V, F=1MHz$	-	0.67	-	Ω

4. Ordering Information

Part No.	Package	Marking
XNT031N04T	TO-220	XNT031N04T

Notes:

1. Repetitive Rating : Pulsed width limited by maximum junction temperature.
2. The data tested by pulsed , pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
3. Essentially independent of operating temperature.



5. Rating And Characteristic Curves

Fig.1 Continuous Drain Current vs. T_C

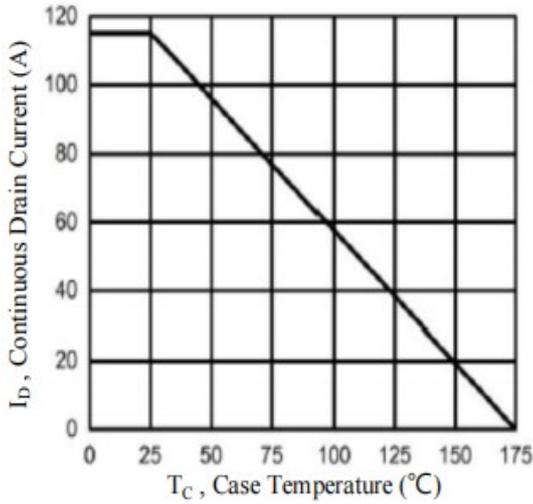


Fig.2 Normalized $R_{DS(on)}$ vs. T_J

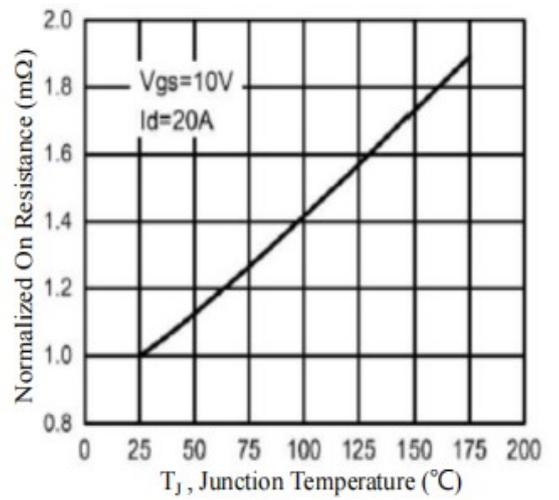


Fig.3 Normalized V_{th} vs. T_J

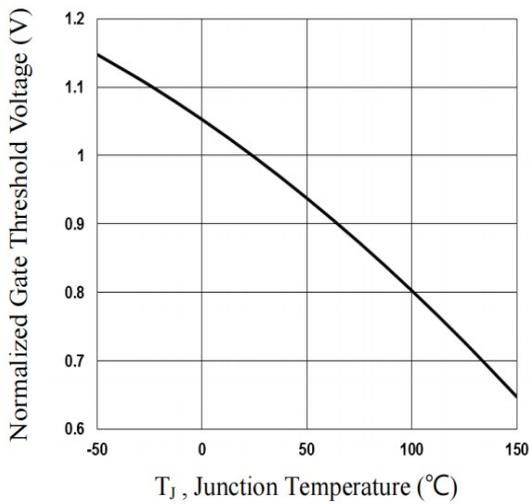


Fig.4 Gate Charge Waveform

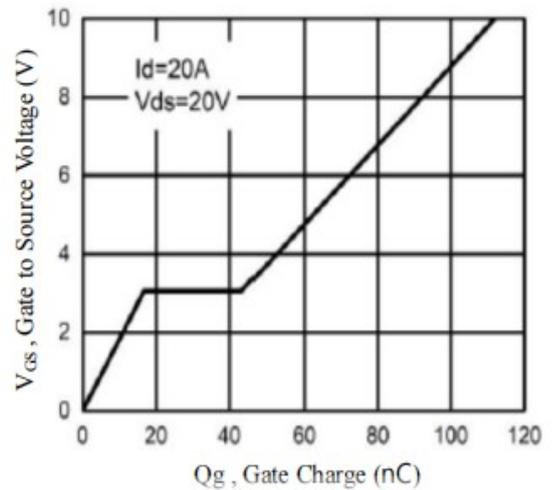


Fig.5 Normalized Transient Impedance

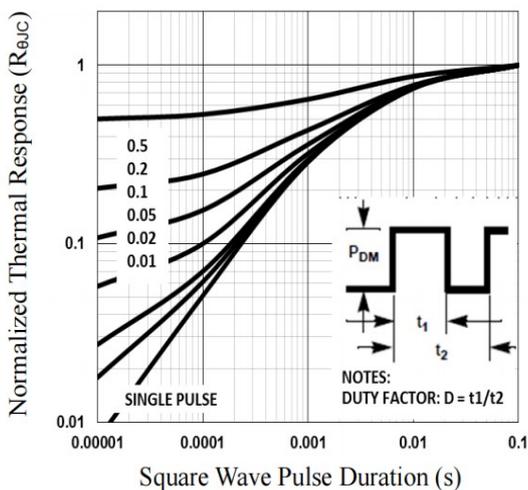
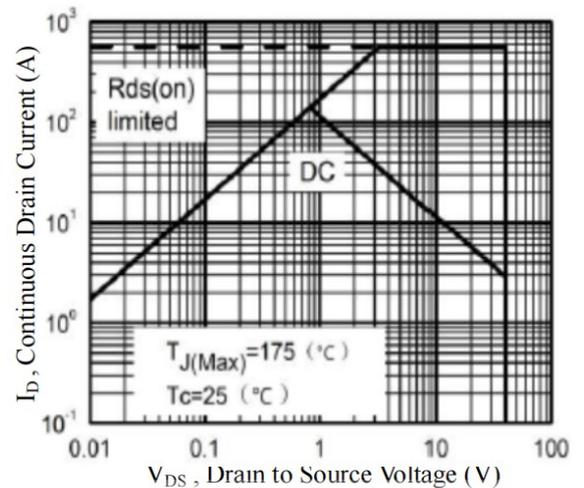


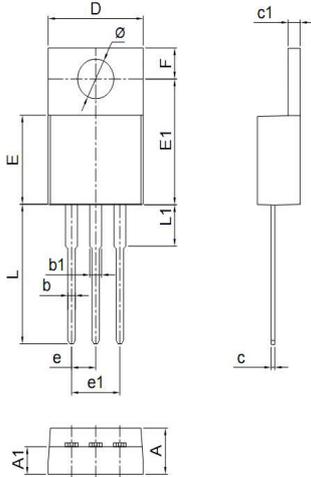
Fig.6 Maximum Safe Operation Area





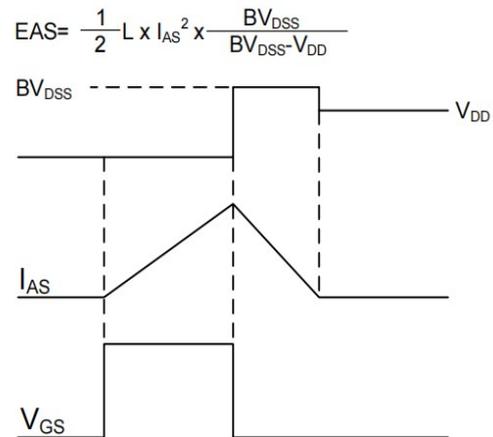
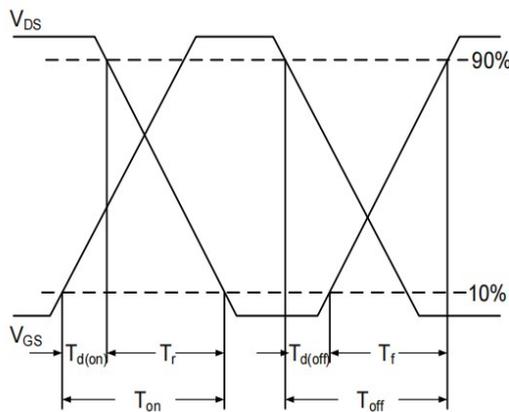
6. Dimensions

TO-220 Mechanical Drawing

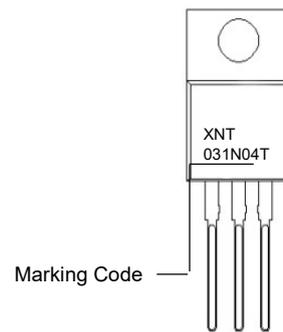
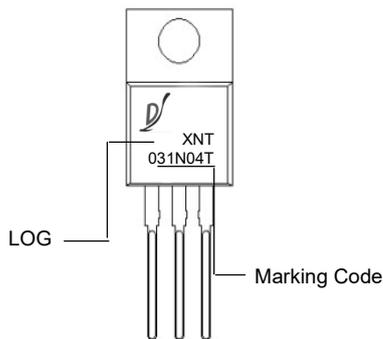


Dimensions	Inches		Millimeters	
	Min	Max	Min	Max
A	0.169	0.184	4.28	4.68
A1	0.083	0.106	2.10	2.70
b	0.024	0.039	0.60	1.00
b1	0.043	0.059	1.10	1.50
c	0.012	0.024	0.30	0.60
c1	0.043	0.059	1.10	1.50
D	0.382	0.406	9.70	10.30
E	0.335	0.366	8.50	9.30
e	0.094	0.104	2.40	2.64
L	0.504	0.535	12.80	13.60
Φ	0.134	0.150	3.40	3.80

7. Test circuits



8. Part Marking System



9. Package Information

Package	Packing Type	Quantity(pcs)
TO-220	Tube	50



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